

N-channel 40 V, 6.3 mΩ standard level MOSFET in LFPAK33 19 September 2016 Product data sheet

1. General description

Standard level N-channel MOSFET in an LFPAK33 (Power33) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Q101 Compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ rating of greater than 1 V at 175 °C

3. Applications

- 12 V automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	70	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	79	W
Static character	eristics	·					
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 20 A; T _j = 25 °C; Fig. 11		-	5.2	6.3	mΩ
Dynamic char	acteristics				-		
Q _{GD}	gate-drain charge	$I_D = 20 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}; \text{ Fig. 13}; \text{ Fig. 14}$		-	9.5	-	nC

[1] Continuous current is limited by package

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	Source		D
2	S	Source		
3	S	Source		G C C C C C C C C C C C C C C C C C C C
4	G	Gate		mbb076 S
mb	D	Mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Table 3. Ordering int	formation		
Type number	Package		
	Name	Description	Version
BUK7M6R3-40E	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 8 leads	SOT1210

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK7M6R3-40E	76E340

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	40	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	79	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	70	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	56.4	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$; Fig. 3		-	319	А
T _{stg}	storage temperature			-55	175	°C

N-channel 40 V, 6.3 mΩ standard level MOSFET in LFPAK33

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C		-	66.1	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	319	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$I_D = 70 \text{ A}; V_{sup} \le 40 \text{ V}; \text{ R}_{GS} = 50 \Omega;$ V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; Fig. 4	[2][3]	-	58.8	mJ

[1] Continuous current is limited by package

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

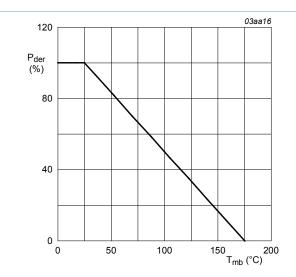


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

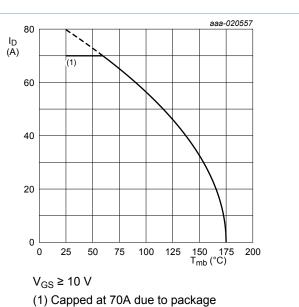
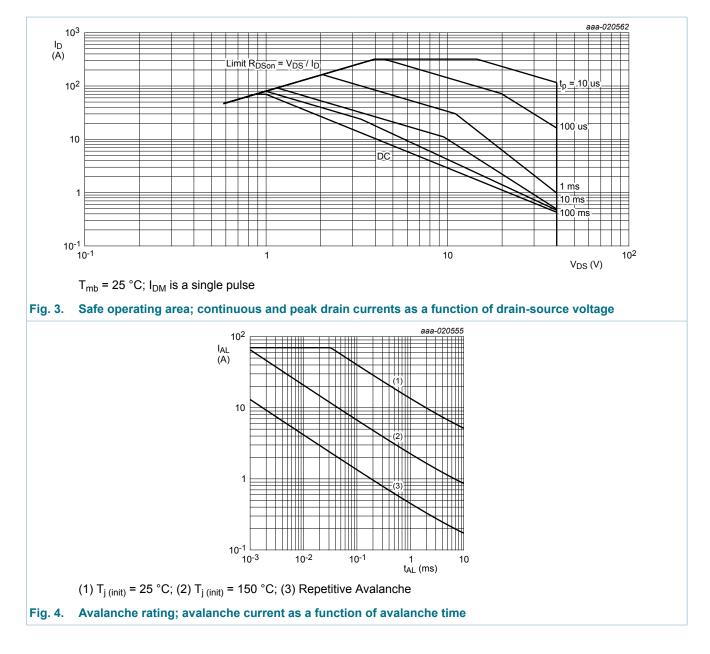


Fig. 2. Continuous drain current as a function of mounting base temperature

$$I_{D(Si)} = 79.5A \times \sqrt{\frac{175^{\circ}C - T_{mb}}{150^{\circ}C}}$$
 for $T_{mb} \ge 25^{\circ}C$

N-channel 40 V, 6.3 m Ω standard level MOSFET in LFPAK33

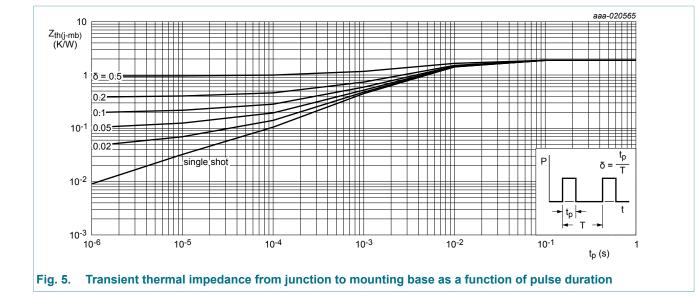


9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>5</u>	_	1.58	1.89	K/W

BUK7M6R3-40E

N-channel 40 V, 6.3 mΩ standard level MOSFET in LFPAK33



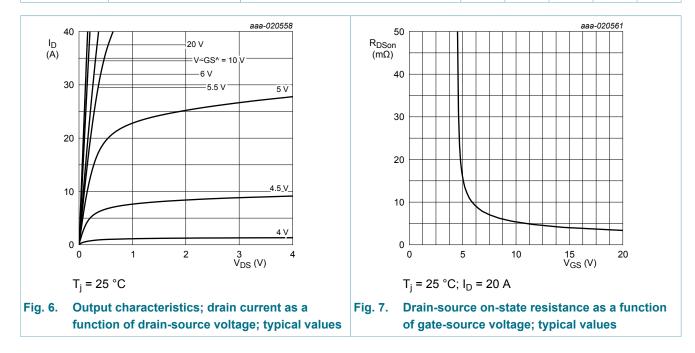
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		I			_
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	40	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	36	-	-	V
V _{GS(th)}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 9; Fig. 10	2.4	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 9	-	-	4.5	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 9	1	-	-	V
I _{DSS}	drain leakage current	V_{DS} = 40 V; V_{GS} = 0 V; T_j = 25 °C	-	0.01	1	μA
		V_{DS} = 40 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 20 A; T _j = 25 °C; Fig. 11	-	5.2	6.3	mΩ
		V _{GS} = 10 V; I _D = 20 A; T _j = 175 °C; Fig. 12	-	-	12.5	mΩ
Dynamic cl	naracteristics		1			
Q _{G(tot)}	total gate charge	I_D = 20 A; V_{DS} = 32 V; V_{GS} = 10 V;	-	28.1	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	7.2	-	nC
Q _{GD}	gate-drain charge	1 1	-	9.5	-	nC

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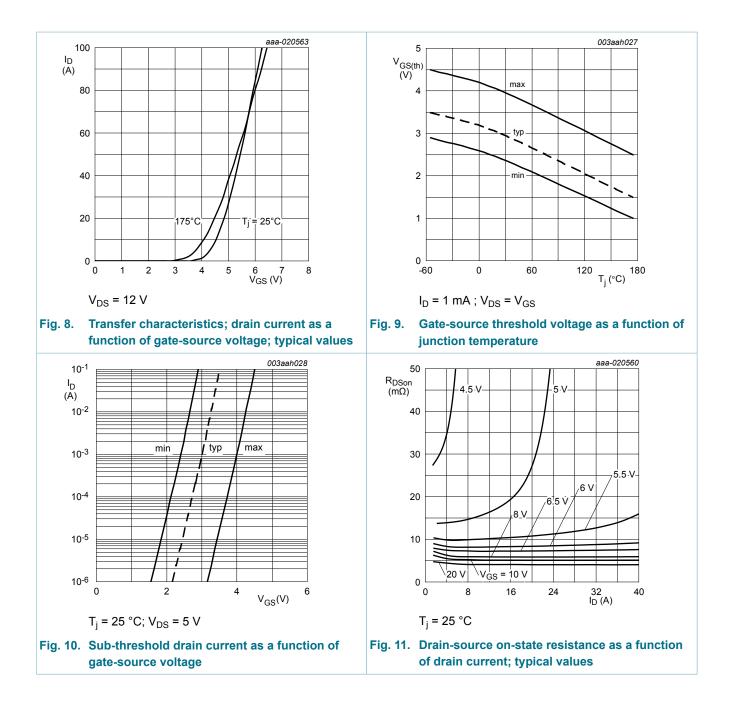
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{iss}	input capacitance	V_{DS} = 25 V; V_{GS} = 0 V; f = 1 MHz;	-	1438	1912	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	 -	279	335	pF
C _{rss}	reverse transfer capacitance		-	169	232	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 1.5 Ω; V _{GS} = 10 V;	-	8.2	-	ns
t _r	rise time	R _{G(ext)} = 5 Ω; T _j = 25 °C	 -	15.7	-	ns
t _{d(off)}	turn-off delay time		-	22.2	-	ns
t _f	fall time		-	17.6	-	ns
Source-dra	ain diode					
V _{SD}	source-drain voltage	I_{S} = 20 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>	-	0.85	1.2	V
t _{rr}	reverse recovery time	I_{S} = 20 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;	-	17.1	-	ns
Q _r	recovered charge	V _{DS} = 25 V; T _j = 25 °C	 -	9.4	-	nC



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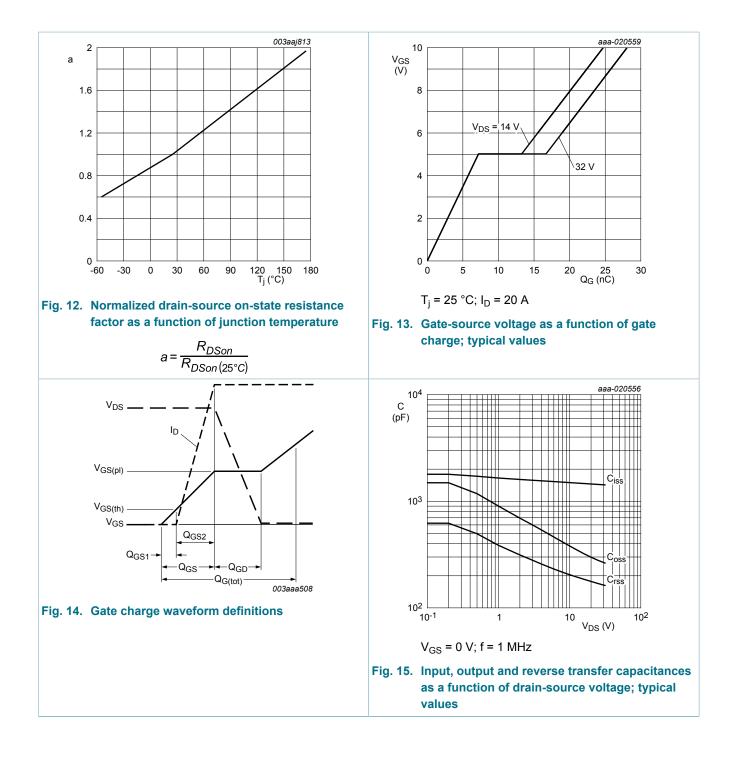
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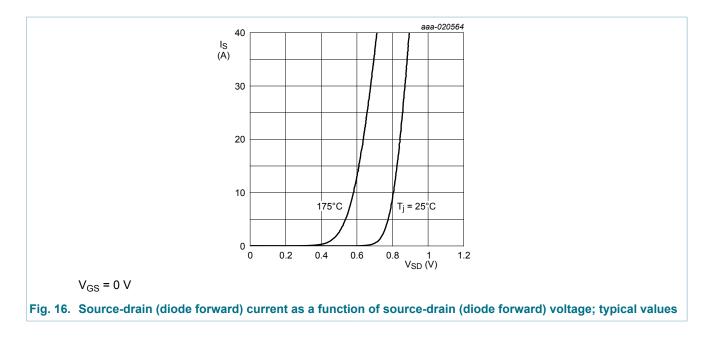
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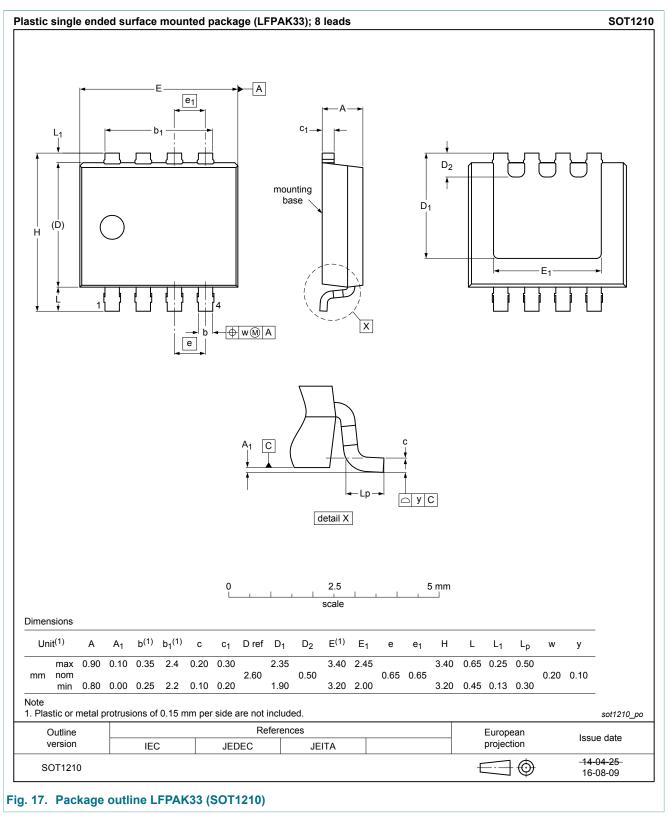


11. Application information

For guidance on how to use and understand this datasheet, please refer to application note <u>AN11158</u> "Understanding power MOSFET datasheet parameters".

N-channel 40 V, 6.3 mΩ standard level MOSFET in LFPAK33

12. Package outline



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13. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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N-channel 40 V, 6.3 mΩ standard level MOSFET in LFPAK33

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14. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	2
9	Thermal characteristics	4
10	Characteristics	5
11	Application information	
11 12		9
••	Application information	9 10
12	Application information Package outline	9 10 11
12 13	Application information Package outline Legal information Data sheet status Definitions	9
12 13 13.1	Application information Package outline Legal information Data sheet status	9

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